

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Masayuki Yasuda

Serial No.: 09/019,087

Filed: 2/05/98



TIJ-24816

Art Unit: 1765

#9
ca
3/1/00

For: MANUFACTURING METHOD OF SEMICONDUCTOR IC DEVICE

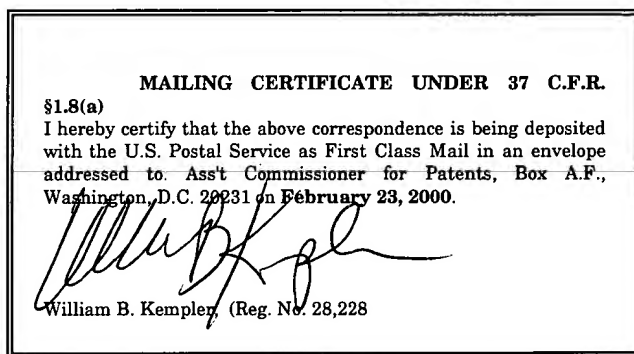
REQUEST FOR RECONSIDERATION

02/23/00

Assistant Commissioner for Patents

Box A.F.

Washington, DC 20231



Applicant requests reconsideration of Claims 1-11 which were rejected by the examiner under 35 U.S.C. Section 103 (A) as being unpatentable over Tsuji '625.

In paragraph 2 of the official action, the examiner states:

“...which is followed by the formation of trenches on said insulating film...”
(emphasis added).

On the last line of page 2, the examiner states that:

“...nor does he disclose the trenches having sidewalls.”

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